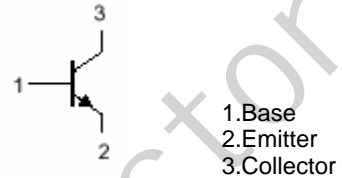


DESCRIPTION

- With TO-3 package
 - Complement to type MJ15023G; MJ15025G
 - Excellent safe operating area
 - High DC current gain
- $h_{FE} = 15$ (Min) @ $I_C = 8$ Adc


APPLICATIONS

- Designed for high power audio, disk head positioners and other linear applications


Absolute maximum ratings(Ta=)

SYMBOL	PARAMETER		CONDITIONS	VALUE	UNIT
V _{CBO}	Collector-base voltage	MJ15022G	Open emitter	350	V
		MJ15024G		400	
V _{CEO}	Collector-emitter voltage	MJ15022G	Open base	200	V
		MJ15024G		250	
V _{EBO}	Emitter-base voltage		Open collector	5	V
I _C	Collector current			16	A
I _{CM}	Collector current-peak			30	A
I _B	Base current			5	A
P _D	Total power dissipation		T _C =25	250	W
T _j	Junction temperature			150	
T _{stg}	Storage temperature			-65~200	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal resistance junction to case	0.70	/W

CHARACTERISTICS

 T_j=25 unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-emitter sustaining voltage	MJ15022	I _C =0.1A ; I _B =0	200			V
		MJ15024		250			
V _{CEsat-1}	Collector-emitter saturation voltage		I _C =8A; I _B =0.8A			1.4	V
V _{CEsat-2}	Collector-emitter saturation voltage		I _C =16A; I _B =3.2A			4.0	V
V _{BE}	Base-emitter on voltage		I _C =8A ; V _{CE} =4V			2.2	V
I _{CEO}	Collector cut-off current	MJ15022G	V _{CE} =150V; I _B =0			0.5	mA
		MJ15024G	V _{CE} =200V; I _B =0				
I _{CEX}	Collector cut-off current	MJ15022G	V _{CE} =200V; V _{BE(off)} =1.5V			0.25	mA
		MJ15024G	V _{CE} =250V; V _{BE(off)} =1.5V				
I _{EBO}	Emitter cut-off current		V _{EB} =5V; I _C =0			0.5	mA
h _{FE-1}	DC current gain		I _C =8A ; V _{CE} =4V	15		60	
h _{FE-2}	DC current gain		I _C =16A ; V _{CE} =4V	5			
I _{s/b}	Second breakdown collector current with base forward biased		V _{CE} =50Vdc,t=0.5 s, V _{CE} =80Vdc,t=0.5 s,Nonrepetitive	5.0 2.0			A
C _{OB}	Output capacitance		I _E =0 ; V _{CB} =10V;f=1.0MHz			500	pF
f _T	Transition frequency		I _C =1A ; V _{CE} =10V;f=1.0MHz	4			MHz

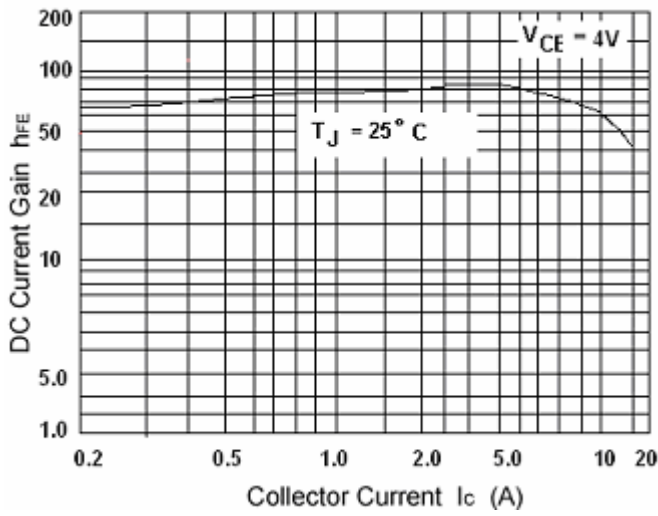


Fig.3 DC current Gain

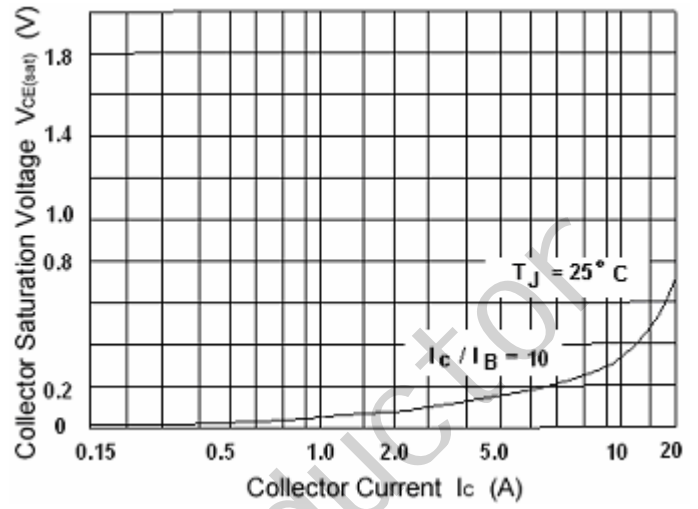


Fig.4 Collector-Emitter Saturation Voltage

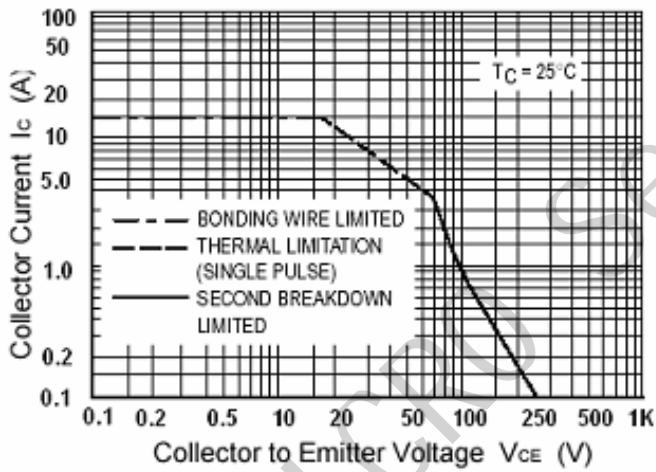


Fig.5 Safe Operating Area

PACKAGE OUTLINE

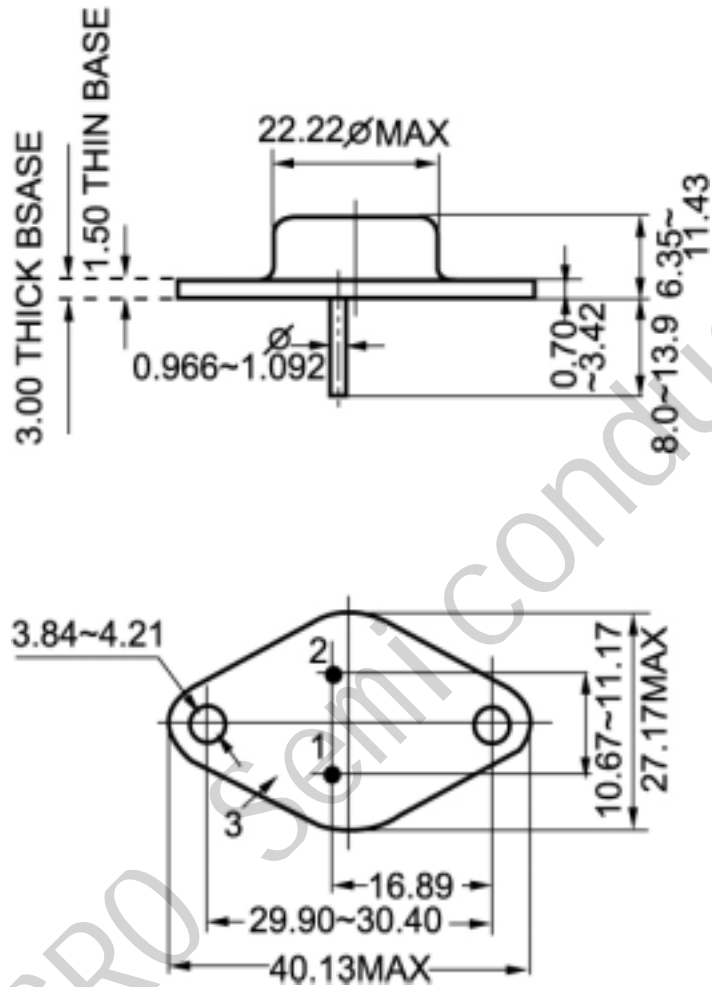


Fig.2 outline dimensions (unindicated tolerance: ± 0.1 mm)

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